### 8-Pin DIP High Speed Transistor Optocouplers

### Single-Channel: 6N135M, 6N136M, HCPL4503M Dual-Channel: HCPL2530M, HCPL2531M

#### Description

The 6N135M, 6N136M, HCPL4503M, HCPL2530M, and HCPL2531M optocouplers consist of an AlGaAs LED optically coupled to a high speed photodetector transistor for each channel.

A separate connection for the bias of the photodiode improves the speed by several orders of magnitude over conventional phototransistor optocouplers by reducing the base-collector capacitance of the input transistor.

The HCPL4503M has no internal connection to the phototransistor base for improved noise immunity. An internal noise shield provides superior common mode rejection of up to  $50,000 \text{ V/}\mu\text{s}$ .

#### **Features**

- High Speed 1 MBit/s
- Dual-Channel: HCPL2530M, HCPL2531M
- CTR Guaranteed 0°C to 70°C
- No Base Connection for Improved Noise Immunity (HCPL4503M)
- Superior CMR of 15,000 V/us Minimum (HCPL4503M)
- Safety and Regulatory Approvals
  - ◆ UL1577, 5,000 VAC<sub>RMS</sub> for 1 Minute
  - ◆ DIN EN/IEC60747-5-5
- These are Pb-Free Devices

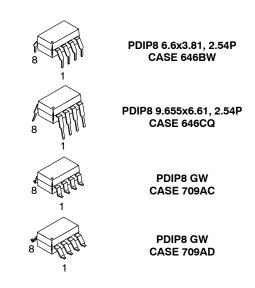
#### **Applications**

- Line Receivers
- Pulse Transformer Replacement
- Output Interface to CMOS-LSTTL-TTL
- Wide-Bandwidth Analog Coupling

#### **Related Resources**

- <a href="https://www.onsemi.com/products/interfaces/high-performance-opto-ouplers">https://www.onsemi.com/products/interfaces/high-performance-opto-ouplers</a>
- https://www.onsemi.com/products/interfaces/high-performance-opto couplers/high-performance-transistor-optocouplers/hcpl0500
- <a href="https://www.onsemi.com/products/interfaces/high-performance-opto-ouplers/high-performance-transistor-optocouplers/fodm452">https://www.onsemi.com/products/interfaces/high-performance-optocouplers/fodm452</a>
- https://www.onsemi.com/products/interfaces/high-performance-optocouplers/low-voltage-high-performance-optocouplers/fod050l

1



### **MARKING DIAGRAM**



6N135 = Device Number

V = DIN EN/IEC60747-5-5 Option (only appears on component ordered with this option)

XX = Two Digit Year Code, e.g., '15'

YY = Two Digit Work Week Ranging from '01' to

B = Assembly Package Code

#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 11 of this data sheet

NOTE: Some of the devices on this data sheet have been **DISCONTINUED**. Please refer to the table on page 11.

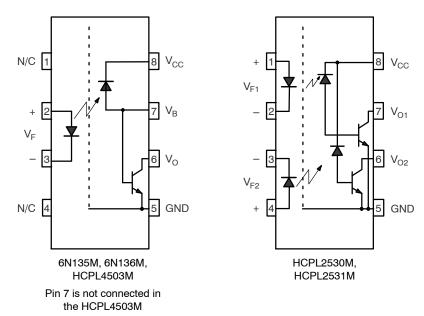


Figure 1. Schematics

**SAFETY AND INSULATION RATINGS** (As per DIN EN/IEC 60747–5–5, this optocoupler is suitable for "safe electrical insulation" only within the safety limit data. Compliance with the safety ratings shall be ensured by means of protective circuits.)

Parameter	Characteristics	
Installation Classifications per DIN VDE 0110/1.89 Table 1, For Rated Mains Voltage	<150 V <sub>RMS</sub>	I–IV
	<300 V <sub>RMS</sub>	I–IV
	<450 V <sub>RMS</sub>	I–III
	<600 V <sub>RMS</sub>	I–III
Climatic Classification		40/100/21
Pollution Degree (DIN VDE 0110/1.89)	2	
Comparative Tracking Index	175	

Symbol	Parameter	Value	Unit
V <sub>PR</sub>	Input-to-Output Test Voltage, Method A, $V_{IORM} x$ 1.6 = $V_{PR}$ , Type and Sample Test with $t_m$ = 10 s, Partial Discharge < 5 pC	1,335	V <sub>peak</sub>
	Input-to-Output Test Voltage, Method B, $V_{IORM} \times 1.875 = V_{PR}$ , 100% Production Test with $t_m = 1$ s, Partial Discharge < 5 pC	1,669	V <sub>peak</sub>
$V_{IORM}$	Maximum Working Insulation Voltage	890	V <sub>peak</sub>
$V_{IOTM}$	Highest Allowable Over-Voltage	6,000	V <sub>peak</sub>
	External Creepage	≥8.0	mm
	External Clearance	≥7.4	mm
	External Clearance (for Option TV, 0.4" Lead Spacing)	≥10.16	mm
DTI	Distance Through Insulation (Insulation Thickness)	≥0.5	mm
T <sub>S</sub>	Case Temperature (Note 1)	150	°C
I <sub>S,INPUT</sub>	Input Current (Note 1)	200	mA
P <sub>S,OUTPUT</sub>	Output Power (Duty Factor ≤ 2.7%) (Note 1)	300	mW
R <sub>IO</sub>	Insulation Resistance at T <sub>S</sub> , V <sub>IO</sub> = 500 V (Note 1)	>10 <sup>9</sup>	Ω

<sup>1.</sup> Safety limit value – maximum values allowed in the event of a failure.

### ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25°C unless otherwise noted)

Symbol	Parameter	Test Conditions	Value	Unit
T <sub>STG</sub>	Storage Temperature		-40 to +125	°C
T <sub>OPR</sub>	Operating Temperature		-40 to +100	°C
TJ	Junction Temperature		-40 to +125	°C
T <sub>SOL</sub>	Lead Solder Temperature		260 for 10 s	°C
EMITTER				
I <sub>F</sub> (avg)	DC/Average Forward Input Current Each Channel (Note 2)		25	mA
I <sub>F</sub> (pk)	Peak Forward Input Current Each Channel (Note 3)	50% Duty Cycle, 1 ms P.W.	50	mA
I <sub>F</sub> (trans)	Peak Transient Input Current Each Channel	≤1 μs P.W., 300 pps	1.0	Α
V <sub>R</sub>	Reverse Input Voltage Each Channel		5	V
P <sub>D</sub>	Input Power Dissipation Each Channel (Note 4)		45	mW
DETECTOR				
I <sub>O</sub> (avg)	Average Output Current Each Channel		8	mA
I <sub>O</sub> (pk)	Peak Output Current Each Channel		16	mA
V <sub>EBR</sub>	Emitter-Base Reverse Voltage	6N135M and 6N136M	5	V
V <sub>CC</sub>	Supply Voltage		-0.5 to 30	V
V <sub>O</sub>	Output Voltage		-0.5 to 20	V
Ι <sub>Β</sub>	Base Current	6N135M and 6N136M	5	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

100

2. Derate linearly above 70°C free-air temperature at a rate of 0.8 mA/°C.

Output Power Dissipation Each Channel (Note 5)

- 3. Derate linearly above 70°C free-air temperature at a rate of 1.6 mA/°C.
- 4. Derate linearly above 70°C free-air temperature at a rate of 0.9 mW/°C.
- 5. Derate linearly above 70°C free-air temperature at a rate of 2.0 mW/°C.

#### RECOMMENDED OPERATING CONDITIONS

 $P_D$ 

Symbol	Parameter	Min	Max	Unit
V <sub>CC</sub>	Supply Voltage	4.5	20.0	V
T <sub>A</sub>	Ambient Operating Temperature	0	70	°C
I <sub>FL</sub>	Input Current, Low Level	0	250	μΑ
I <sub>FH</sub>	Input Current, High Level (Note 6)	6.3	20.0	mA

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

<sup>6. 6.3</sup> mA is a guard banded value which allows for at least 20% CTR degradation. Initial input current threshold value is 5.0 mA or less.

### **ELECTRICAL CHARACTERISTICS**

Symbol	Parameter	Device	Test Conditions	Min	Тур	Max	Unit
INDIVIDUAL COMPONENT CHARACTERISTICS ( $V_{CC} = 5.0 \text{ V}$ , $T_A = 0^{\circ}\text{C}$ to $70^{\circ}\text{C}$ unless otherwise specified.)							
EMITTER							
V <sub>F</sub>	Input Forward Voltage	All	I <sub>F</sub> = 16 mA, T <sub>A</sub> = 25°C	-	1.45	1.70	V
		All	I <sub>F</sub> = 16 mA	-	-	1.80	
B <sub>VR</sub>	Input Reverse Breakdown Voltage	All	I <sub>R</sub> = 10 μA	5	21	-	V
$\Delta V_F/\Delta T_A$	Temperature Coefficient of Forward Voltage	All	I <sub>F</sub> = 16 mA	_	-1.7	-	mV/°C
DETECTO	R						
	Logic High Output	All	$I_F = 0 \text{ mA}, V_O = V_{CC} = 5.5 \text{ V}, T_A = 25^{\circ}\text{C}$	-	0.0007	0.5	μΑ
I <sub>OH</sub>	Current	6N135M, 6N136M, HCPL4503M	$I_F = 0 \text{ mA}, V_O = V_{CC} = 15 \text{ V}, T_A = 25^{\circ}\text{C}$	-	0.0019	1	
		All	$I_F = 0 \text{ mA}, V_O = V_{CC} = 15 \text{ V}$	_	-	50	
I <sub>CCL</sub>	Logic Low Supply Current	6N135M, 6N136M, HCPL4503M	$I_F$ = 16 mA, $V_O$ = Open, $V_{CC}$ = 15 V	-	163	200	μΑ
OOL		HCPL2530M, HCPL2531M	$I_{F1} = I_{F2} = 16 \text{ mA}, V_O = \text{Open},$ $V_{CC} = 15 \text{ V}$	_	-	400	
Іссн	Logic High Supply Current	6N135M, 6N136M, HCPL4503M	$I_F = 0$ mA, $V_O = Open$ , $V_{CC} = 15$ V	-	0.0004	2	μΑ
		HCPL2530M, HCPL2531M	$I_F = 0$ mA, $V_O = Open$ , $V_{CC} = 15$ V	-	-	4	

**TRANSFER CHARACTERISTICS** ( $T_A = 0^{\circ}C$  to  $70^{\circ}C$  unless otherwise specified.)

COUPLED	COUPLED							
CTR	Current Transfer Ratio (Note 7)	6N135M, HCPL2530M	$I_F = 16 \text{ mA}, V_O = 0.4 \text{ V}, V_{CC} = 4.5 \text{ V},$ $T_A = 25^{\circ}\text{C}$		7	38	50	%
		6N136M, HCPL4503M, HCPL2531M			19	38	50	%
		6N135M	$I_F = 16 \text{ mA}, V_{CC} = 4.5 \text{ V}$	V <sub>OL</sub> = 0.4 V	5	_	-	%
		HCPL2530M		V <sub>OL</sub> = 0.5 V				
		6N136M, HCPL4503M		V <sub>OL</sub> = 0.4 V	15	-	-	%
		HCPL2531M		V <sub>OL</sub> = 0.5 V				
V <sub>OL</sub>	Logic LOW Output	6N135M	I <sub>F</sub> = 16 mA, I <sub>O</sub> = 1.1 mA, \	/ <sub>CC</sub> = 4.5 V,	-	0.12	0.4	V
	Voltage	HCPL2530M	T <sub>A</sub> = 25°C				0.5	
		6N136M, HCPL4503M	$I_F = 16 \text{ mA}, I_O = 3 \text{ mA}, V_O$ $T_A = 25^{\circ}\text{C}$	<sub>C</sub> = 4.5 V,	-	0.20	0.4	
		HCPL2531M					0.5	
		6N135M, HCPL2530M	$I_F = 16 \text{ mA}, I_O = 0.8 \text{ mA}, V$	/ <sub>CC</sub> = 4.5 V	-	0.11	0.5	
		HCPL4503M, HCPL2531M	$I_F = 16 \text{ mA}, I_O = 2.4 \text{ mA}, V$	/ <sub>CC</sub> = 4.5 V	-	0.18	0.5	

### **ELECTRICAL CHARACTERISTICS** (continued)

Symbol	Parameter	Device	Test Conditions	Min	Тур	Max	Unit
SWITCHIN	IG CHARACTERISTICS (T	- A = 0°C to 70°C ι	unless otherwise specified.)				•
t <sub>PHL</sub>	Propagation Delay Time	6N135M	$T_A = 25^{\circ}C$ , $R_L = 4.1 \text{ k}\Omega$ , $I_F = 16 \text{ mA}$	_	0.23	1.5	μs
	to Logic LOW	HCPL2530M	(Note 8) (Figure 14)		0.25		
		6N136M, HCPL4503M	$T_A$ = 25°C, $R_L$ = 1.9 k $\Omega$ , $I_F$ = 16 mA (Note 9) (Figure 14)	_	0.25	0.8	μs
		HCPL2531M			0.28		
		6N135M, HCPL2530M	$R_L$ = 4.1 kΩ, $I_F$ = 16 mA (Note 8) (Figure 14)	_	-	2.0	μs
		6N136M, HCPL4503M, HCPL2531M	$R_L$ = 1.9 kΩ, $I_F$ = 16 mA (Note 9) (Figure 14)	-	-	1.0	μs
t <sub>PLH</sub>	Propagation Delay Time	6N135M	$T_A = 25^{\circ}C$ , $R_L = 4.1 \text{ k}\Omega$ , $I_F = 16 \text{ mA}$	_	0.45	1.5	μs
	to Logic HIGH	o Logic HIGH (Note 8) (Figure 14)		0.29			
		6N136M, HCPL4503M	$T_A$ = 25°C, $R_L$ = 1.9 k $\Omega$ , $I_F$ = 16 mA (Note 9) (Figure 14)	-	0.26	0.8	μS
		HCPL2531M			0.18		
		6N135M, HCPL2530M	$R_L$ = 4.1 kΩ, $I_F$ = 16 mA (Note 8) (Figure 14)	_	-	2.0	μs
		6N136M, HCPL4503M, HCPL2531M	$R_L$ = 1.9 kΩ, $I_F$ = 16 mA (Note 9) (Figure 14)	-	-	1.0	μs
CM <sub>H</sub>	Common Mode Transient Immunity	6N135M, HCPL2530M	$I_F$ = 0 mA, $V_{CM}$ = 10 $V_{P-P}$ , $R_L$ = 4.1 kΩ, $T_A$ = 25°C (Note 10) (Figure 15)	-	10,000	-	V/μs
	at Logic High	6N136M, HCPL2531M	$I_F$ = 0 mA, $V_{CM}$ = 10 $V_{P-P}$ , $R_L$ = 1.9 kΩ, $T_A$ = 25°C (Note 10) (Figure 15)	-	10,000	-	
		HCPL4503M	$I_F$ = 0 mA, $V_{CM}$ = 1,500 $V_{P-P}$ , $R_L$ = 4.1 kΩ, $T_A$ = 25°C (Note 10) (Figure 15)	15,000	50,000	-	
CM <sub>L</sub>	Common Mode Transient Immunity	6N135M, HCPL2530M	$I_F$ = 16 mA, $V_{CM}$ = 10 $V_{P-P}$ , $R_L$ = 4.1 kΩ, $T_A$ = 25°C (Note 10) (Figure 16)	-	10,000	_	V/μs
	at Logic Low	6N136M, HCPL2531M	$I_F$ = 16 mA, $V_{CM}$ = 10 $V_{P-P}$ , $R_L$ = 1.9 kΩ (Note 10) (Figure 15)	-	10,000	-	
		HCPL4503M	$I_F$ = 16 mA, $V_{CM}$ = 1,500 $V_{P-P}$ , $R_L$ = 4.1 kΩ, $T_A$ = 25°C (Note 10) (Figure 15)	15,000	50,000	-	

#### **ELECTRICAL CHARACTERISTICS** (continued)

Symbol	Parameter	Device	Test Conditions	Min	Тур	Max	Unit
ISOLATIO	ISOLATION CHARACTERISTICS (T <sub>A</sub> = 25°C, unless otherwise noted.)						
V <sub>ISO</sub>	Withstand Isolation Test Voltage	All	RH $\leq$ 50%, I <sub>I-O</sub> $\leq$ 10 $\mu$ A t = 1 minute, f = 50 Hz (Note 11) (Note 13)	5,000	-	-	VAC <sub>RM</sub> s
R <sub>I-O</sub>	Resistance (Input to Output)	All	V <sub>I-O</sub> = 500 V <sub>DC</sub> (Note 11)	-	10 <sup>11</sup>	_	Ω
C <sub>I-O</sub>	Capacitance (Input to Output)	All	f = 1 MHz, V <sub>I-O</sub> = 0 V <sub>DC</sub> (Note 11)	-	1	-	pF
I <sub>I-I</sub>	Input-Input Insulation Leakage Current	HCPL2530M, HCPL2531M	RH $\leq$ 45%, V <sub>I-I</sub> = 500 V <sub>DC</sub> , t = 5 s (Note 12)	-	<1	-	nA
R <sub>I-I</sub>	Input-Input Resistance	HCPL2530M, HCPL2531M	V <sub>I-I</sub> = 500 V <sub>DC</sub> (Note 12)	-	10 <sup>12</sup>	-	Ω
C <sub>I-I</sub>	Input-Input Capacitance	HCPL2530M, HCPL2531M	f = 1 MHz (Note 12)	-	0.2	П	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

- 7. Current Transfer Ratio is defined as a ratio of output collector current, I<sub>O</sub>, to the forward LED input current, I<sub>F</sub>, times 100%.
- 8. The 4.1 k $\Omega$  load represents 1 LSTTL unit load of 0.36 mA and 6.1 k $\Omega$  pull-up resistor.
- 9. The 1.9 k $\Omega$  load represents 1 TTL unit load of 1.6 mA and 5.6 k $\Omega$  pull-up resistor.
- 10. Common mode transient immunity in logic high level is the maximum tolerable (positive) dV<sub>cm</sub>/dt on the leading edge of the common mode pulse signal, V<sub>CM</sub>, to assure that the output will remain in a logic high state (i.e., V<sub>O</sub> > 2.0 V).
  Common mode transient immunity in logic low level is the maximum tolerable (negative) dV<sub>cm</sub>/dt on the trailing edge of the common mode pulse signal, V<sub>CM</sub>, to assure that the output will remain in a logic low state (i.e., V<sub>O</sub> < 0.8 V).</p>
- 11. Device is considered a two terminal device: pins 1, 2, 3 and 4 are shorted together and pins 5, 6, 7 and 8 are shorted together.
- 12. Measured between pins 1 and 2 shorted together, and pins 3 and 4 shorted together.
- 13.5000 V<sub>RMS</sub> for 1 minute duration is equivalent to 6000 V<sub>RMS</sub> for 1 second duration.

#### **TYPICAL PERFORMANCE CURVES**

(For single-channel devices; 6N135M, 6N136M, and HCPL4503M.)

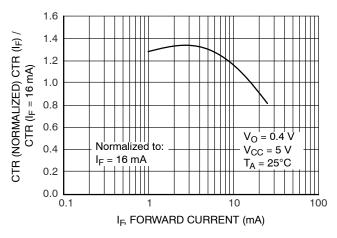


Figure 2. Normalized CTR vs. Forward Current

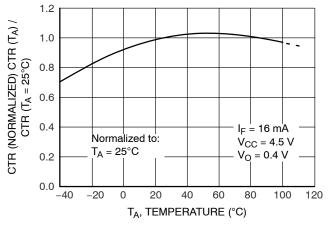


Figure 3. Normalized CTR vs. Temperature

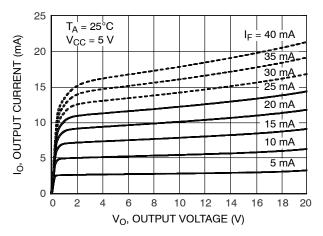


Figure 4. Output Current vs. Output Voltage

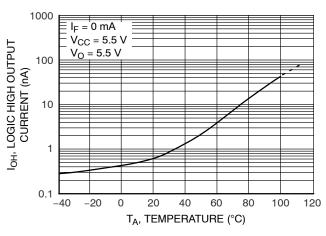


Figure 5. Logic High Output Current vs. Temperature

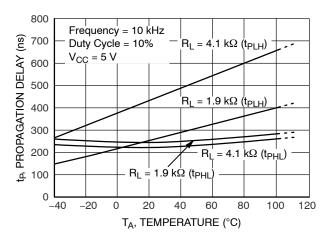


Figure 6. Propagation Delay vs. Temperature

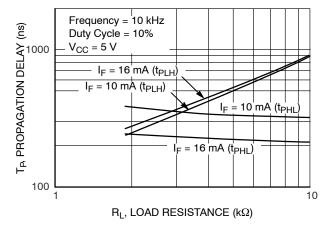


Figure 7. Propagation Delay vs. Load Resistance

#### **TYPICAL PERFORMANCE CURVES**

(For dual-channel devices; HCPL2530M and HCPL2531M.)

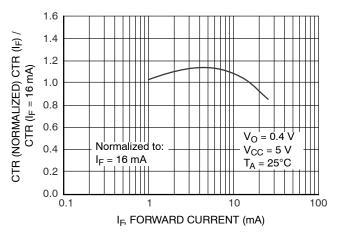


Figure 8. Normalized CTR vs. Forward Current

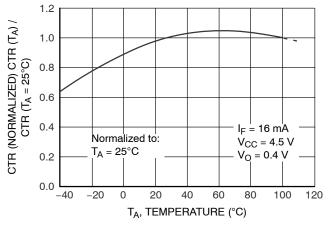


Figure 9. Normalized CTR vs. Temperature

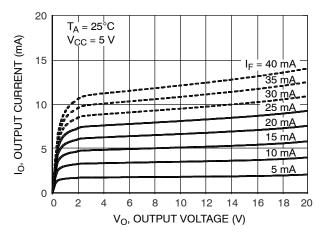


Figure 10. Output Current vs. Output Voltage

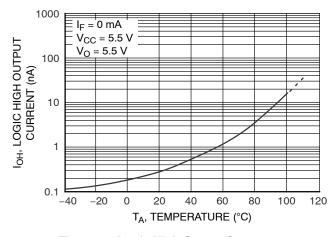


Figure 11. Logic High Output Current vs.
Temperature

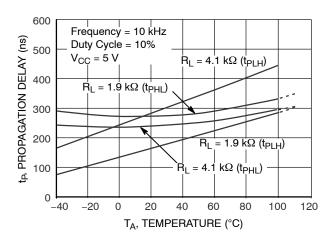


Figure 12. Propagation Delay vs. Temperature

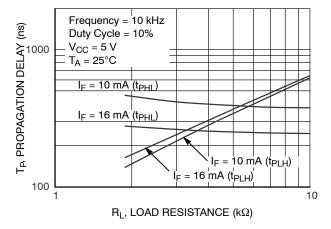
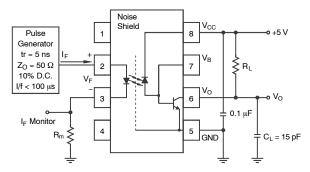
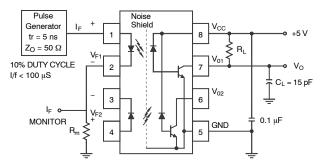


Figure 13. Propagation Delay vs. Load Resistance





Test Circuit for 6N135M, 6N136M, and HCPL4503M

Test Circuit for HCPL2530M and HCPL2531M

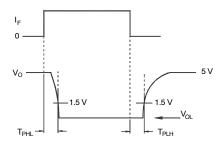
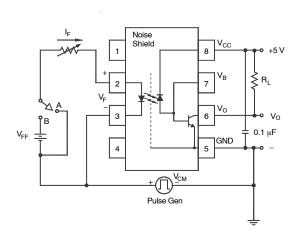
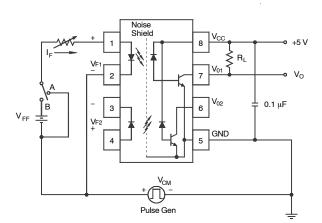


Figure 14. Switching Time Test Circuit



Test Circuit for 6N135M, 6N136M, and HCPL4503M



Test Circuit for HCPL2530M and HCPL2531M

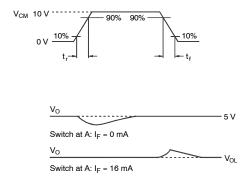
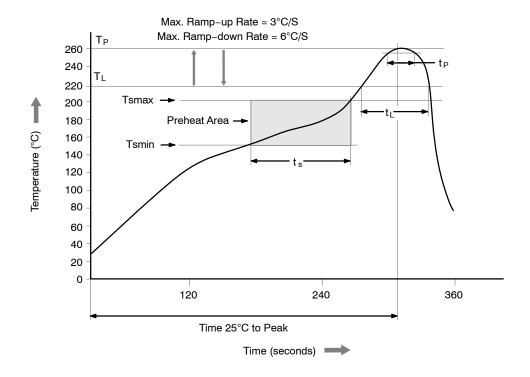


Figure 15. Common Mode Immunity Test Circuit



Profile Feature	Pb-Free Assembly Profile
Temperature Min. (Tsmin)	150°C
Temperature Max. (Tsmax)	200°C
Time (t <sub>S</sub> ) from (Tsmin to Tsmax)	60 to 120 s
Ramp-up Rate (t <sub>L</sub> to t <sub>P</sub> )	3°C/second maximum
Liquidous Temperature (T <sub>L</sub> )	217°C
Time (t <sub>L</sub> ) Maintained Above (T <sub>L</sub> )	60 to 150 s
Peak Body Package Temperature	260°C +0°C / -5°C
Time (t <sub>P</sub> ) within 5°C of 260°C	30 s
Ramp-down Rate (T <sub>P</sub> to T <sub>L</sub> )	6°C/s maximum
Time 25°C to Peak Temperature	8 minutes maximum

Figure 16. Reflow Profile

### **ORDERING INFORMATION**

Part Number	Package	Shipping <sup>†</sup>
6N135M	PDIP8 9.655x6.61, 2.54P DIP 8–Pin	50 Units / Tube
6N135SM	PDIP8 GW SMT 8-Pin (Lead Bend)	50 Units / Tube
6N135SDM	PDIP8 GW SMT 8-Pin (Lead Bend)	1,000 / Tape and Reel
6N135VM	PDIP8 9.655x6.61, 2.54P DIP 8-Pin, DIN IEC60747-5-5 Option	50 Units / Tube
6N135SVM	PDIP8 GW SMT 8-Pin (Lead Bend), DIN EN/IEC 60747-5-5 Option	50 Units / Tube
6N135SDVM	PDIP8 GW SMT 8-Pin (Lead Bend), DIN EN/IEC 60747-5-5 Option	1,000 / Tape and Reel
6N135TSVM	PDIP8 GW SMT 8-Pin, 0.4" Lead Spacing, DIN EN/IEC 60747-5-5 Option	50 Units / Tube
6N135TSR2VM	PDIP8 GW SMT 8-Pin, 0.4" Lead Spacing, DIN EN/IEC 60747-5-2 Option	1,000 / Tape and Reel

#### **DISCONTINUED** (Note 14)

6N135TVM	PDIP8 6.6x3.81, 2.54P	50 Units / Tube
	DIP 8-Pin, 0.4" Lead Spacing, DIN EN/IEC 60747-5-5 Option	

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

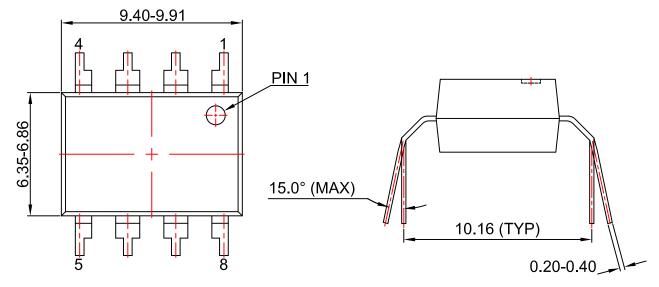
NOTE: The product orderable part number system listed in this table also applies to the 6N136M, HCPL4503M, HCPL2530M and HCPL2531M product families.

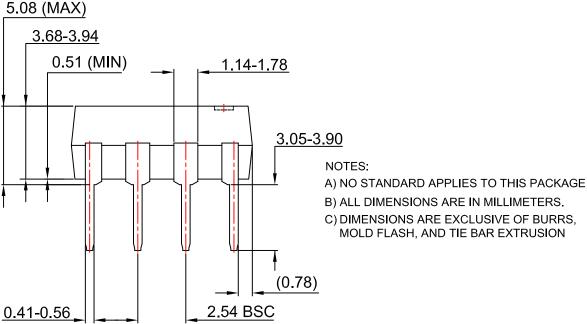
<sup>14.</sup> **DISCONTINUED:** This device is not recommended for new design. Please contact your **onsemi** representative for information. The most current information on this device may be available on <a href="https://www.onsemi.com">www.onsemi.com</a>.



#### PDIP8 6.6x3.81, 2.54P CASE 646BW ISSUE O

**DATE 31 JUL 2016** 



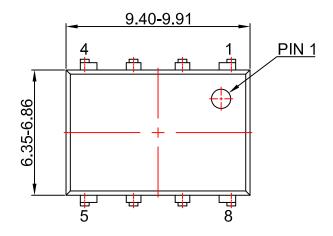


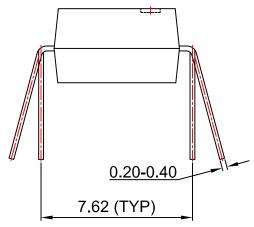
DOCUMENT NUMBER:	98AON13445G	Electronic versions are uncontrolled except when accessed directly from the Document Repositor Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.		
DESCRIPTION:	PDIP8 6.6X3.81, 2.54P		PAGE 1 OF 1	

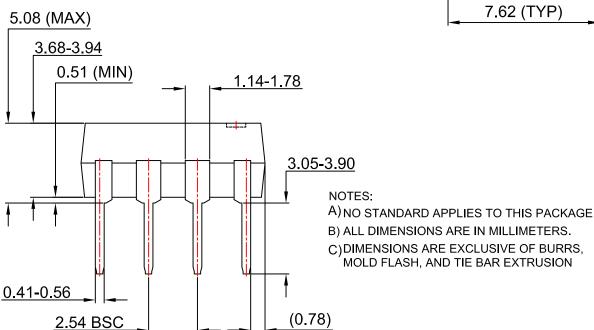


#### PDIP8 9.655x6.6, 2.54P CASE 646CQ ISSUE O

**DATE 18 SEP 2017** 





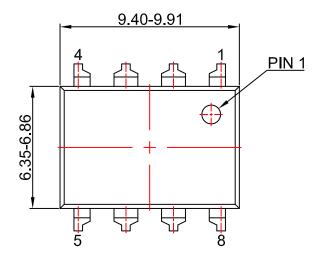


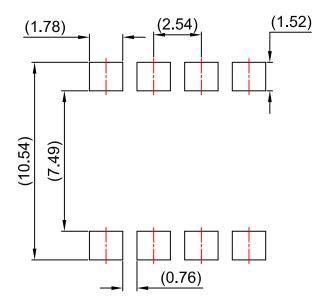
DOCUMENT NUMBER:	98AON13446G	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	PDIP8 9.655X6.6, 2.54P		PAGE 1 OF 1



PDIP8 GW CASE 709AC ISSUE O

**DATE 31 JUL 2016** 





5.08 (MAX)

3.68-3.94

0.51 (MIN)

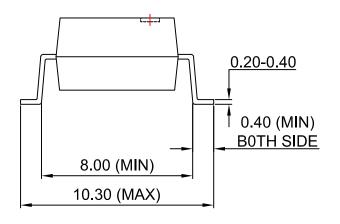
1.14-1.78

(0.78)

2.54BSC

0.41-0.56





### NOTES:

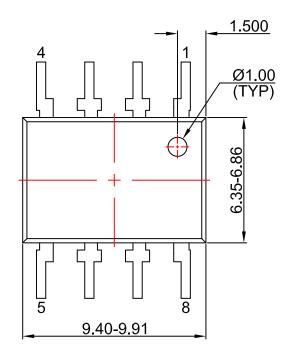
- A) NO STANDARD APPLIES TO THIS PACKAGE
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSION

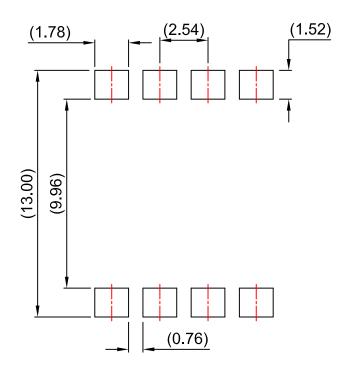
DOCUMENT NUMBER:	98AON13447G	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	PDIP8 GW		PAGE 1 OF 1



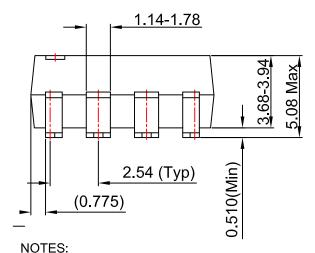
PDIP8 GW CASE 709AD ISSUE O

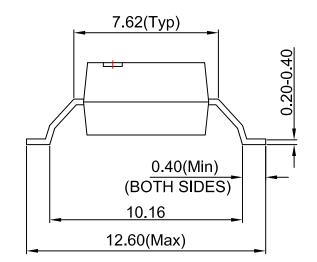
**DATE 31 JUL 2016** 





LAND PATTERN RECOMMENDATION





#### .....

- A) NO STANDARD APPLIES TO THIS PACKAGE
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSION

DOCUMENT NUMBER:	98AON13448G	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	PDIP8 GW		PAGE 1 OF 1

onsemi, ONSEMI., and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <a href="www.onsemi.com/site/pdf/Patent-Marking.pdf">www.onsemi.com/site/pdf/Patent-Marking.pdf</a>. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems. or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

#### ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

 $\textbf{Technical Library:} \ \underline{www.onsemi.com/design/resources/technical-documentation}$ 

onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at

www.onsemi.com/support/sales